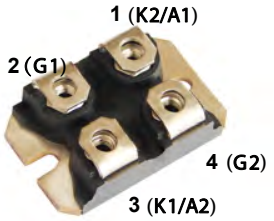
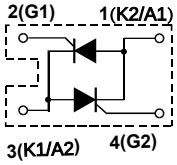
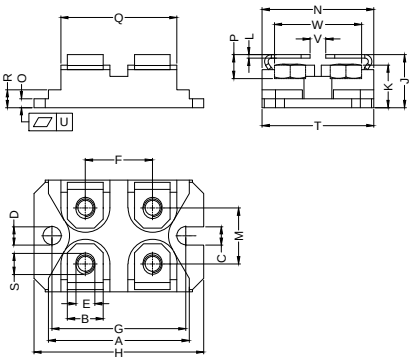
SSAC62G16S

Anti-Parallel Thyristor-Thyristor Modules(Solid State AC Switches)





Dimensions SOT-227



Dim.	Millimeter		Dim.	Millimeter	
	Min.	Max.		Min.	Max.
A	31.30	31.62	M	12.20	14.00
B	7.80	8.20	N	25.15	25.62
C	4.09	4.29	O	1.98	2.13
D	4.09	4.29	P	4.15	4.62
E	4.09	4.29	Q	25.90	26.30
F	14.91	15.11	R	3.94	4.42
G	30.12	30.30	S	4.45	4.85
H	38.20	38.56	T	24.59	25.07
J	12.30	12.90	U	0.05	0.10
K	8.92	9.60	V	3.00	4.80
L	0.76	0.84	W	19.81	21.08

Type	V_{RSM} V_{DSM} V	V_{RRM} V_{DRM} V
SSAC62G08S	800	800
SSAC62G12S	1200	1200
SSAC62G14S	1400	1400
SSAC62G16S	1600	1600
SSAC62G18S	1800	1800

Symbol	Test Conditions		Maximum Ratings	Unit
I_{RMS} I_{TRMS} I_{TAVM}	T_C = 110°C, 50 - 400 Hz, module T_{VJ} = T_{VJM} T_C = 110°C; (180° sine)		54 39 25	A
I_{TSM}	T_{VJ}=45°C V_R=0	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	400 300	A
	T_{VJ}=T_{VJM} V_R=0	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	350 370	
I^2t	T_{VJ}=45°C V_R=0	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	800 780	A^2s
	T_{VJ}=T_{VJM} V_R=0	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	610 570	
$(di/dt)_{cr}$	T_{VJ}=T_{VJM} f=50Hz, t_p=200us V_D=2/3V_{DRM} I_G=0.3A di_G/dt=0.3A/us	repetitive, I_T=150A non repetitive, I_T=I_{TAVM}	100 500	A/us
$(dv/dt)_{cr}$	T_{VJ}=T_{VJM}; R_{GK}=∞; method 1 (linear voltage rise)	V_{DR}=2/3V_{DRM}	1000	V/us
P_{GM} P_{GAVM}	T_{VJ}=T_{VJM} I_T=I_{TAVM}	t_p=30us t_p=300us	10 5 0.5	W
V_{RGM}			10	V
T_{VJ} T_{VJM} T_{stg}			-40...+150 150 -40...+150	°C
V_{ISOL}	50/60Hz, RMS I_{ISOL}≤1mA		2500	V~
M_d	Mounting torque (M4) Terminal connection torque (M4)		1.1-1.5/9-13 1.1-1.5/9-13	Nm/lb.in.
Weight	typical		30	g

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Symbol	Test Conditions	Characteristic Values	Unit
I_R, I_D	$T_{VJ}=T_{VJM}$; $V_R=V_{RRM}$; $V_D=V_{DRM}$	≤12	mA
V_T	I_T=45A; T_{VJ}=25°C	≤1.57	V
V_{TO}	For power-loss calculations only	≤0.85	V
r_T		≤12	mΩ
V_{GT}	V_D=6V; T_{VJ}=25°C T_{VJ}=-40°C	≤1.5 ≤1.6	V
I_{GT}	V_D=6V; T_{VJ}=25°C T_{VJ}=-40°C	≤100 ≤150	mA
V_{GD}	$T_{VJ}=T_{VJM}$; V_D=2/3V_{DRM}	≤0.2	V
I_{GD}		≤5	mA
I_L	T_{VJ}=25°C; t_p=10us I_G=0.3A; di_G/dt=0.3A/us	≤250	
I_H	T_{VJ}=25°C; V_D=6V; R_{GK}=∞	≤100	
t_{gd}	T_{VJ}=25°C; V_D=1/2V_{DRM} I_G=0.3A; di_G/dt=0.3A/us	≤2	us
t_q	$T_{VJ}=T_{VJM}$; I_T=20A; t_p=200us; di/dt=-10A/us typ. V_R=100V; dv/dt=15V/us; V_D=2/3V_{DRM}	≤150	
R_{thJC}	per thyristor; DC current per module	≤0.91 ≤0.455	K/W
R_{thCH}	per thyristor; DC current typ. per module typ.	≤0.1 ≤0.05	
d_S	Creeping distance on surface	≤8	mm
d_A	Creepage distance in air	≤4	
a	Max. allowable acceleration	≤50	m/s^2

FEATURES

* Thyristor controller for AC for mains frequency
* International standard package SOT-227
* Isolation voltage 2500V~
* Glass passivated chips
* UL File NO. E310749
* RoHS compliant

APPLICATIONS

* Switching and control of single and three phase AC Softstart
* AC motor controller
* Solid state Switches
* Light and temperature control

ADVANTAGES

* Easy to mount with two screws
* Space and weight savings
* Improved temperature and power cycling
* High power density

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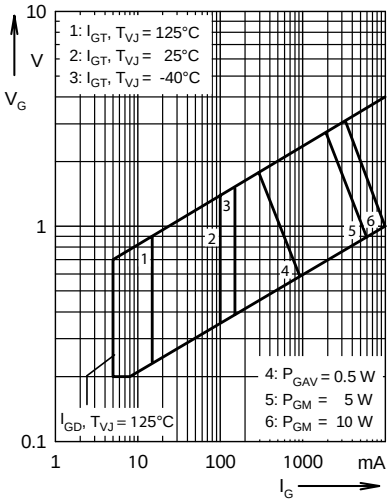

Fig. 1 Gate trigger characteristics

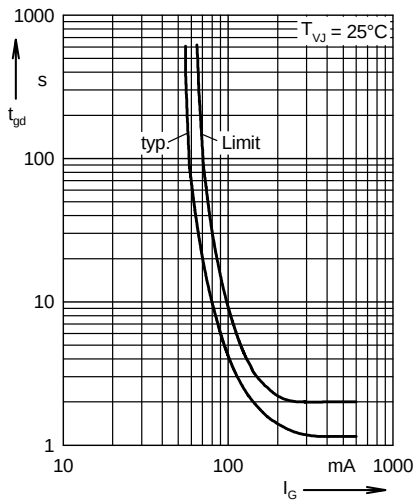

Fig. 2 Gate trigger delay time

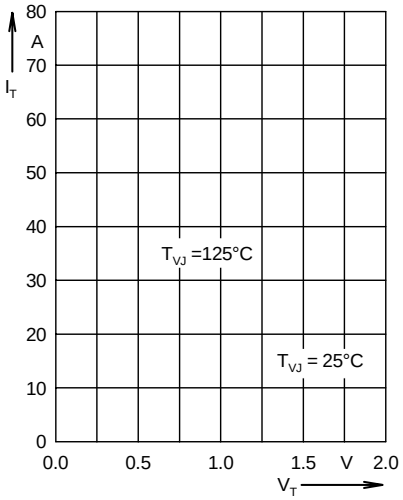

Fig. 3 Forward current versus voltage drop per leg

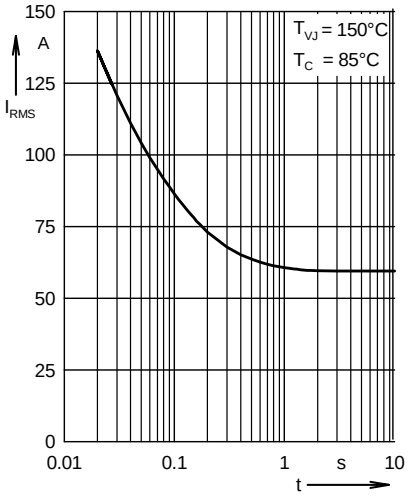

Fig. 4 Rated RMS current versus time (360° conduction)

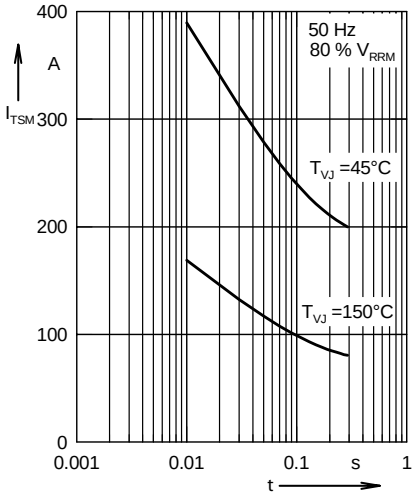

Fig. 5 Surge overload current

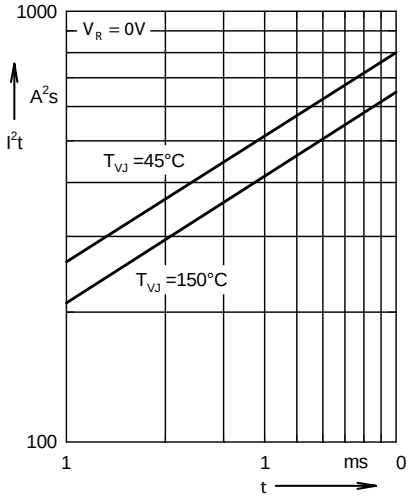

Fig. 7 I²t versus time (per thyristor)

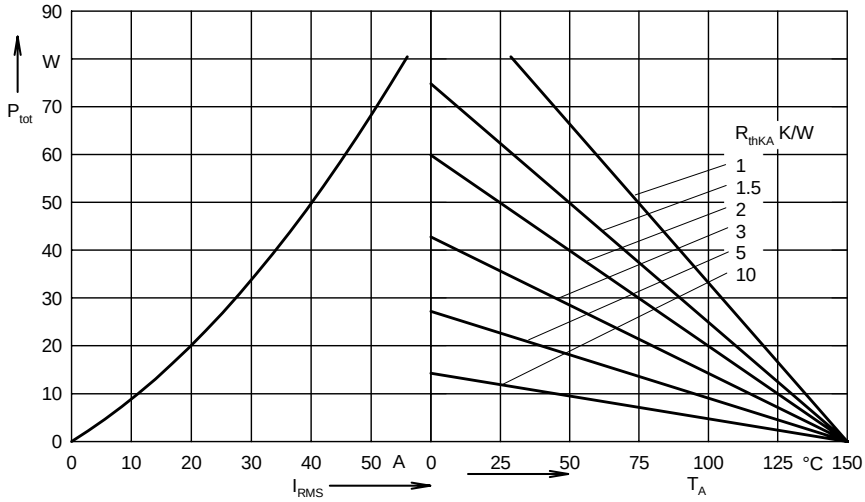

Fig. 6 Load current capability for single AC controller; 1 x SSAC62

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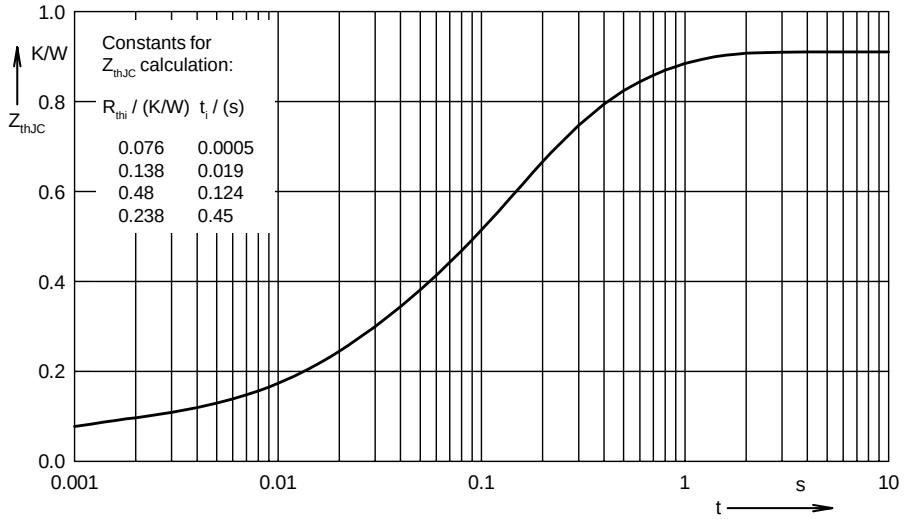

Fig. 8 Transient thermal impedance junction to case (per thyristor)

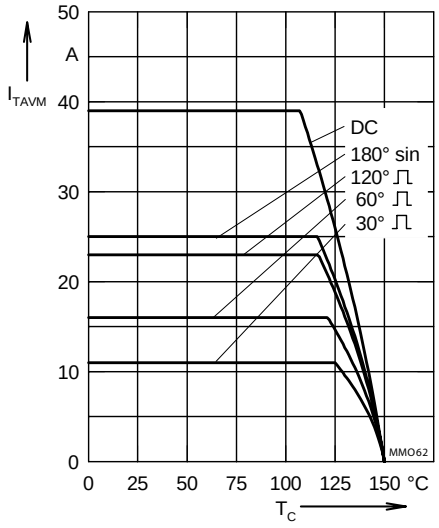

Fig. 9 Maximum forward current at case temperature

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